

# HS-302RH/883S, HS-303RH/883S, HS-306RH/883S, HS-307RH/883S, HS-384RH/883S, HS-390RH/883S Radiation Hardened

September 1995

# Features

- This Circuit is Processed in Accordance to Mil-Std-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Radiation Hardened
  - Functional Total Dose Exceeds 1 x 10<sup>5</sup> RAD Si
- Pin for Pin Compatible with Intersil HI-3XX Series Analog Switches
- Analog Signal Range 15V
- Low Leakage
- Low R<sub>ON</sub>
- No Latch Up
- Versions for 5V and 15V Digital Systems
- Low Operating Power
- Military Temperature Range -55°C to +125°C

### Applications

- Sample and Hold i.e. Low Leakage Switching
- Op Amp Gain Switching i.e. Low ON Resistance
- Switched Capacitor Filters
- Low Level Switching Circuits
- Satellites
- Nuclear Reactor Controls

Ordering Information

Military Environments

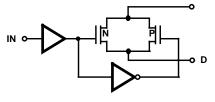
### Description

The HS-3XXRH/883S family of analog switches are monolithic devices fabricated using Radiation Hardened CMOS technology and the Intersil dielectric isolation process for latch-up free operation. Improved total dose hardness is obtained by layout (thin oxide tabs extending to a channel stop) and processing (hardened gate oxide). These switches offer low-resistance switching performance for analog voltages up to the supply rails. "ON" resistance is low and stays reasonably constant over the full range of operating voltage and current. "ON" resistance also stays reasonably constant when exposed to radiation, being typically  $30\Omega$  pre-rad and  $35\Omega$  post 100K RAD-Si. All devices provide break-before-make switching.

**CMOS Analog Switches** 

The 6 devices in this switch series are differentiated by type of switch action, pinout and digital logic levels. The HS-302/ 303/384/390RH/883S switches have 5V digital inputs while the HS-306/307RH/883S switches have 15V digital inputs. All devices are available in Ceramic Flatpack and SBDIP packages. The HS-3XXRH/883S switches can directly replace the HI-3XX series devices.

### Functional Diagram



| PART NUMBER             | TEMPERATURE RANGE | SCREENING LEVEL                  | PACKAGE                  |
|-------------------------|-------------------|----------------------------------|--------------------------|
| HS1-302RH/883S          | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead SBDIP            |
| HS9-302RH/883S          | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead Ceramic Flatpack |
| HS1-302RH/Sample        | +25°C             | Sample                           | 14 Lead SBDIP            |
| HS9-302RH/Sample        | +25°C             | Sample                           | 14 Lead Ceramic Flatpack |
| HS1-303RH/883S          | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead SBDIP            |
| HS9-303RH/883S          | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead Ceramic Flatpack |
| HS1-303RH/Sample        | +25°C             | Sample                           | 14 Lead SBDIP            |
| HS9-303RH/Sample        | +25°C             | Sample                           | 14 Lead Ceramic Flatpack |
| HS1-306RH/883S (Note 1) | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead SBDIP            |
| HS9-306RH/883S (Note 1) | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead Ceramic Flatpack |

CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures. http://www.intersil.com or 407-727-9207 | Copyright © Intersil Corporation 1999

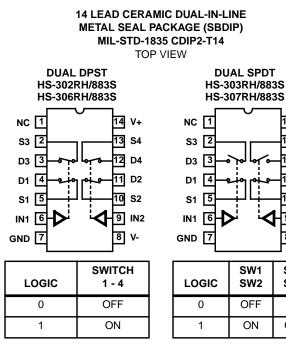
| PART NUMBER               | TEMPERATURE RANGE | SCREENING LEVEL                  | PACKAGE                  |
|---------------------------|-------------------|----------------------------------|--------------------------|
| HS1-306RH/Sample (Note 1) | +25°C             | Sample                           | 14 Lead SBDIP            |
| HS9-306RH/Sample (Note 1) | +25°C             | Sample                           | 14 Lead Ceramic Flatpack |
| HS1-307RH/883S            | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead SBDIP            |
| HS9-307RH/883S            | -55°C to +125°C   | Intersil /883 Class S Equivalent | 14 Lead Ceramic Flatpack |
| HS1-307RH/Sample          | +25°C             | Sample                           | 14 Lead SBDIP            |
| HS9-307RH/Sample          | +25°C             | Sample                           | 14 Lead Ceramic Flatpack |
| HS1-384RH/883S (Note 1)   | -55°C to +125°C   | Intersil /883 Class S Equivalent | 16 Lead SBDIP            |
| HS9-384RH/883S (Note 1)   | -55°C to +125°C   | Intersil /883 Class S Equivalent | 16 Lead Ceramic Flatpack |
| HS1-384RH/Sample (Note 1) | +25°C             | Sample                           | 16 Lead SBDIP            |
| HS9-384RH/Sample (Note 1) | +25°C             | Sample                           | 16 Lead Ceramic Flatpack |
| HS1-390RH/883S            | -55°C to +125°C   | Intersil /883 Class S Equivalent | 16 Lead SBDIP            |
| HS9-390RH/883S            | -55°C to +125°C   | Intersil /883 Class S Equivalent | 16 Lead Ceramic Flatpack |
| HS1-390RH/Sample          | +25°C             | Sample                           | 16 Lead SBDIP            |
| HS9-390RH/Sample          | +25°C             | Sample                           | 16 Lead Ceramic Flatpack |

## Ordering Information (Continued)

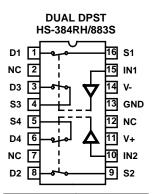
NOTE:

1. Not recommended for new design.

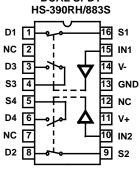
### **Pinouts** (Switch States are for Logic "1" Inputs)



#### 16 LEAD CERAMIC DUAL-IN-LINE METAL SEAL PACKAGE (SBDIP) MIL-STD-1835 CDIP2-T16 TOP VIEW



| LOGIC | SWITCH<br>1 - 4 |
|-------|-----------------|
| 0     | OFF             |
| 1     | ON              |



DUAL SPDT

| LOGIC | SW1<br>SW2 | SW3<br>SW4 |  |  |
|-------|------------|------------|--|--|
| 0     | OFF        | ON         |  |  |
| 1     | ON         | OFF        |  |  |

14 V+

13 S4

D4

S2

9 IN2

8 V-

SW3

SW4

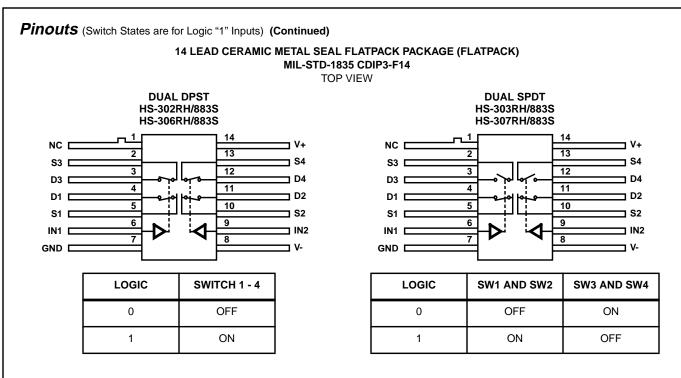
ON

OFF

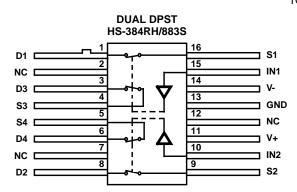
12

11 D2

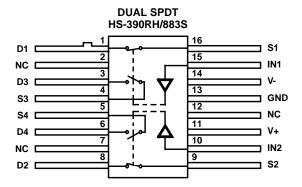
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#### 16 LEAD CERAMIC METAL SEAL FLATPACK PACKAGE (FLATPACK) MIL-STD-1835 CDIP4-F16 TOP VIEW



| LOGIC | SWITCH 1 - 4 |
|-------|--------------|
| 0     | OFF          |
| 1     | ON           |



| LOGIC | SW1 AND SW2 | SW3 AND SW4 |
|-------|-------------|-------------|
| 0     | OFF         | ON          |
| 1     | ON          | OFF         |

### **Absolute Maximum Ratings**

| Reliability Information |
|-------------------------|
|-------------------------|

| Supply Voltage Between V+ and V- +44V   +VSUPPLY to Ground +22V   -VSUPPLY to Ground -22V | Τł  |
|---|-----|
| Analog Input Overvoltages:  |     |
| +VS+VSUPPLY +1.5V   |     |
| -VS   | Μ   |
| Digital Input Overvoltage:  |     |
| +VA+VSUPPLY +4V   |     |
| -VAVSUPPLY -4V  |     |
| Peak Current, S or D Pulsed at 1ms, 10% Duty Cycle Max 40mA                               |     |
| Continuous Current  | lf  |
| Storage Temperature Range   | siı |
| Junction Temperature  |     |
| Lead Temperature (soldering 10s)≤+300°C   |     |
|   |     |

| Thermal Resistance                               | $\theta_{JA}$            | $\theta_{JC}$         |
|--|--------------------------|-----------------------|
| 14 Lead SBDIP Package                            | 70°C/W                   | 19ºC/W                |
| 14 Lead Ceramic Flatpack Package                 | 105°C/W                  | 17ºC/W                |
| 16 Lead SBDIP Package                            | 70°C/W                   | 19 <sup>o</sup> C/W   |
| 16 Lead Ceramic Flatpack Package                 | 105°C/W                  | 17ºC/W                |
| Maximum Package Power Dissipation at +12         | 5 <sup>o</sup> C Ambient | t                     |
| 14 Lead SBDIP Package                            |                          | 0.71W                 |
| 14 Lead Ceramic Flatpack Package                 |                          | 0.48W                 |
| 16 Lead SBDIP Package                            |                          | 0.71W                 |
| 16 Lead Ceramic Flatpack Package                 |                          | 0.48                  |
| If device power exceeds package dissipation      | capability, pr           | ovide heat            |
| sinking or derate linearly at the following rate | :                        |                       |
| 14 Lead SBDIP Package                            | 1                        | 4.3mW/ <sup>o</sup> C |
| 14 Lead Ceramic Flatpack Package                 |                          | 9.5mW/ºC              |
| 16 Lead SBDIP Package                            | 1                        | 4.3mW/ <sup>o</sup> C |
| 16 Lead Ceramic Flatpack Package                 |                          | 9.5mW/ <sup>o</sup> C |
|  |                          |                       |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### **Operating Conditions**

| Operating Supply Voltage (± VSupply) ±15V | Operating Temperature Range55° | C to +125°C |
|---|--------------------------------|-------------|
|---|--------------------------------|-------------|

#### TABLE 1. HS-302RH/303RH/384RH/390RH/883S DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Guaranteed and 100% Tested. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +4.0V, VAL = 0.8V

|   |   |                                      | GROUP A<br>SUB- |                 | LIMITS |     |       |
|---|---|--------------------------------------|-----------------|-----------------|--------|-----|-------|
| PARAMETER                                       | SYMBOL  | CONDITIONS                           | GROUPS          | TEMPERATURE     | MIN    | МАХ | UNITS |
| "Switch On" Resistance                          | +RDS  | VD = 10V, IS = -10mA,<br>S1/S2/S3/S4 | 1               | +25°C           | -      | 50  | Ω     |
|   |   | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -      | 75  | Ω     |
|   | -RDS  |                                      | 1               | +25°C           | -      | 50  | Ω     |
|   |   | S1/S2/S3/S4                          | 2, 3            | -55°C to +125°C | -      | 75  | Ω     |
| Leakage Current Into                            | +IS(OFF)                                      | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1               | +25°C           | -2     | 2   | nA    |
| the Source Terminal of<br>an "Off" Switch       |   | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100   | 100 | nA    |
|   | -IS(OFF)                                      | VS = -14V, VD = +14V,                | 1               | +25°C           | -2     | 2   | nA    |
|   | S1/S2/S3/S4                                   | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100   | 100 | nA    |
| Leakage Current into                            | +ID(OFF) VS = -14V, VD = +14V<br>S1/S2/S3/S4  | VS = -14V, VD = +14V,                | 1               | +25°C           | -2     | 2   | nA    |
| the Drain Terminal of an<br>"Off" Switch        |   | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100   | 100 | nA    |
| -11   | -ID(OFF) VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1                                    | +25°C           | -2              | 2      | nA  |       |
|   |   | 2, 3                                 | -55°C to +125°C | -100            | 100    | nA  |       |
| Leakage Current from<br>an "On" Driver Into the | +ID(ON) VS = VD = +14V,<br>S1/S2/S3/S4        | 1                                    | +25°C           | -2              | 2      | nA  |       |
| Switch (Drain & Source)                         |   | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100   | 100 | nA    |
|   | -ID(ON)                                       | VS = VD = -14V,                      | 1               | +25°C           | -2     | 2   | nA    |
|   | S1/S2/S3/S4                                   | 2, 3                                 | -55°C to +125°C | -100            | 100    | nA  |       |
| Low Level Input                                 | IAL   | All Channels VA = 0.8V               | 1               | +25°C           | -1     | 1   | μA    |
| Address Current                                 |   |                                      | 2, 3            | -55°C to +125°C | -1     | 1   | μA    |
| High Level Input                                | IAH   | All Channels VA = 4.0V               | 1               | +25°C           | -1     | 1   | μΑ    |
| Address Current                                 |   |                                      | 2, 3            | -55°C to +125°C | -1     | 1   | μA    |

|                                 |                      |                          | GROUP A         |                 | LIMITS  |       |    |
|---------------------------------|----------------------|--------------------------|-----------------|-----------------|---------|-------|----|
| PARAMETER                       | SYMBOL               | CONDITIONS               | SUB-<br>GROUPS  | TEMPERATURE     | MIN MAX | UNITS |    |
| Positive Supply Current         | l(+)                 | All Channels VA = 0.8V   | 1               | +25°C           | -       | 10    | μA |
|                                 |                      |                          | 2, 3            | -55°C to +125°C | -       | 100   | μA |
|                                 |                      | VA1 = 0V, VA2 = 4.0V and | 1               | +25°C           | -       | 0.5   | mA |
|                                 | VA1 = 4.0V, VA2 = 0V | 2, 3                     | -55°C to +125°C | -               | 1       | mA    |    |
| Negative Supply I(-)<br>Current | l(-)                 | All Channels VA = 0.8V   | 1               | +25°C           | -10     | -     | μA |
|                                 |                      |                          | 2, 3            | -55°C to +125°C | -100    | -     | μA |
|                                 |                      | VA1 = 0V, VA2 = 4.0V and | 1               | +25°C           | -10     | -     | μA |
|                                 | VA1 = 4.0V, VA2 = 0V | 2, 3                     | -55°C to +125°C | -100            | -       | μA    |    |

### TABLE 1. HS-302RH/303RH/384RH/390RH/883S DC ELECTRICAL PERFORMANCE CHARACTERISTICS

### TABLE 1. HS-306RH/307RH/883S DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Guaranteed and 100% Tested. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +11.0V, VAL = 3.5V

|   |          |                                      | GROUP A<br>SUB- |                 | LIN  | IITS |       |
|---|----------|--------------------------------------|-----------------|-----------------|------|------|-------|
| PARAMETER                                       | SYMBOL   | CONDITIONS                           | GROUPS          | TEMPERATURE     | MIN  | МАХ  | UNITS |
| "Switch On" Resistance                          | +RDS     | VD = 10V, IS = -10mA,<br>S1/S2/S3/S4 | 1               | +25°C           | -    | 50   | Ω     |
|   |          | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -    | 75   | Ω     |
|   | +RDS     | VD = -10V, IS = 10mA,<br>S1/S2/S3/S4 | 1               | +25°C           | -    | 50   | Ω     |
|   |          | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -    | 75   | Ω     |
| Leakage Current Into                            | +IS(OFF) | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1               | +25°C           | -2   | 2    | nA    |
| the Source Terminal of<br>an "Off" Switch       |          | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
| -1  | -IS(OFF) | VS = -14V, VD = +14V,                | 1               | +25°C           | -2   | 2    | Ω     |
|   |          | S1/S2/S3/S4                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
| Leakage Current into                            | +ID(OFF) | VS = -14V, VD = +14V,                | 1               | +25°C           | -2   | 2    | nA    |
| the Drain Terminal of an<br>"Off" Switch        |          | S1/S2/S3/S4                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
|   | -ID(OFF) | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1               | +25°C           | -2   | 2    | nA    |
|   |          | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
| Leakage Current from<br>an "On" Driver Into the | +ID(ON)  | VS = VD = +14V,<br>S1/S2/S3/S4       | 1               | +25°C           | -2   | 2    | nA    |
| Switch (Drain and                               |          | 51/52/53/54                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
| Source)   | -ID(ON)  | VS = VD = -14V,                      | 1               | +25°C           | -2   | 2    | nA    |
|   |          | S1/S2/S3/S4                          | 2, 3            | -55°C to +125°C | -100 | 100  | nA    |
| Low Level Input<br>Address Current              | IAL      | All Channels VA = 3.5V               | 1               | +25°C           | -1   | 1    | μA    |
| Address Current                                 |          |                                      | 1, 2            | -55°C to +125°C | -1   | 1    | μA    |
| High Level Input<br>Address Current             | IAH      | All Channels VA = 11V                | 1               | +25°C           | -1   | 1    | μA    |
| Audress Current                                 |          |                                      | 1, 2            | -55°C to +125°C | -1   | 1    | μΑ    |

|                         |        |                       | GROUP A        |                 |      | IITS |    |
|-------------------------|--------|-----------------------|----------------|-----------------|------|------|----|
| PARAMETER               | SYMBOL | CONDITIONS            | SUB-<br>GROUPS | TEMPERATURE     | MIN  | МАХ  |    |
| Positive Supply Current | l(+)   | All Channels VA = 0V  | 1              | +25°C           | -    | 10   | μΑ |
|                         |        |                       | 2, 3           | -55°C to +125°C | -    | 100  | μA |
|                         |        | All Channels VA = 15V | 1              | +25°C           | -    | 10   | μA |
|                         |        |                       | 2, 3           | -55°C to +125°C | -    | 100  | μA |
| Negative Supply         | l(-)   | All Channels VA = 0V  | 1              | +25°C           | -10  | -    | μA |
| Current                 |        |                       | 2, 3           | -55°C to +125°C | -100 | -    | μΑ |
|                         |        | All Channels VA = 15V | 1              | +25°C           | -10  | -    | μA |
|                         |        |                       | 2, 3           | -55°C to +125°C | -100 | -    | μΑ |

### TABLE 1. HS-306RH/307RH/883S DC ELECTRICAL PERFORMANCE CHARACTERISTICS

d 100% Tested Unless Otherwise Specified:  $V_{c} = 15V_{c} V_{c} = +15V_{c} VAH = +11.0V_{c} VAH = 3.5V_{c}$ 

### TABLE 2. HS-302RH/303RH/384RH/390RH/883S AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Guaranteed and 100% Tested. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +4.0V, VAL = 0V

|   |        |                                  | GROUP A<br>SUB- |                 | LIN | IITS |       |
|---|--------|----------------------------------|-----------------|-----------------|-----|------|-------|
| PARAMETER                                 | SYMBOL | CONDITIONS                       | GROUPS          | TEMPERATURE     | MIN | МАХ  | UNITS |
| Break-Before-Make<br>Time Delay (HS-303RH | TOPEN  | RL = 300Ω, VS = +3V,<br>VAH = 5V | 9               | +25°C           | 30  | 150  | ns    |
| & 390RH Only)                             |        | VAIT = 31                        | 10, 11          | -55°C to +125°C | -   | 300  | ns    |
| Switch Turn "On" Time                     | TON    | RL = 300Ω, VS = +3V              | 9               | +25°C           | -   | 300  | ns    |
|   |        |                                  | 10, 11          | -55°C to +125°C | -   | 500  | ns    |
| Switch Turn "Off" Time                    | TOFF   | RL = 300Ω, VS = +3V              | 9               | +25°C           | -   | 250  | ns    |
|   |        |                                  | 10, 11          | -55°C to +125°C | -   | 450  | ns    |

### TABLE 2. HS-306RH/307RH/883S AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Guaranteed and 100% Tested. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +15.0V, VAL = 0V

|   |        |                     | GROUP A<br>SUB- |                 | LIM | IITS |       |
|---|--------|---------------------|-----------------|-----------------|-----|------|-------|
| PARAMETER                                 | SYMBOL | CONDITIONS          | GROUPS          | TEMPERATURE     | MIN | МАХ  | UNITS |
| Break-Before-Make<br>Time Delay (HS-307RH | TOPEN  | RL = 300Ω, VS = +3V | 9               | +25°C           | 30  | 150  | ns    |
| Only)                                     |        |                     | 10, 11          | -55°C to +125°C | -   | 300  | ns    |
| Switch Turn "On" Time                     | TON    | RL = 300Ω, VS = +3V | 9               | +25°C           | -   | 300  | ns    |
|   |        |                     | 10, 11          | -55°C to +125°C | -   | 500  | ns    |
| Switch Turn "Off" Time                    | TOFF   | RL = 300Ω, VS = +3V | 9               | +25°C           | -   | 250  | ns    |
|   |        |                     | 10, 11          | -55°C to +125°C | -   | 450  | ns    |

### TABLE 3. HS-302RH/303RH/306RH/307RH/384RH/390RH/883S ELECTRICAL PERFORMANCE CHARACTERISTICS (NOTE 1)

Unless Otherwise Specified: HS-302RH/303RH/384RH/390RH/883S V- = -15V, V+ = +15V, VAH = +4.0V, VAL = 0V HS-306RH/307RH/883S V- = -15V, V+ = +15V, VAH = +15.0V, VAL = 0V

|                          |          | (NOTE 1)               |             | LIN | IITS |       |
|--------------------------|----------|------------------------|-------------|-----|------|-------|
| PARAMETER                | SYMBOL   | CONDITIONS             | TEMPERATURE | MIN | MAX  | UNITS |
| Switch Input Capacitance | CIS(OFF) | Measured Source to GND | +25°C       | -   | 28   | pF    |
| Driver Input Capacitance | CC1      | VA = 0V                | +25°C       | -   | 10   | pF    |
|                          | CC2      | VA = 15V               | +25°C       | -   | 10   | pF    |
| Switch Output            | COS      | Measured Drain to GND  | +25°C       | -   | 28   | pF    |
| Off Isolation            | VISO     | VGEN = 1Vp-p, f = 1MHz | +25°C       | 40  | -    | dB    |
| Crosstalk                | VCR      | VGEN = 1Vp-p, f = 1MHz | +25°C       | 40  | -    | dB    |
| Charge Transfer          | VCTE     | VS = GND, CL = 0.01µF  | +25°C       | -   | 15   | mV    |

NOTE:1. Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.

### TABLE 4. HS-302RH/303RH/384RH/390RH/883S DC POST 100K RAD (Si) ELECTRICAL CHARACTERISTICS

Tested Per Mil-Std-883. Unless Otherwise Specified: HS-302RH/303RH/384RH/390RH/883S V- = -15V, V+ = +15V, VAH = +4.0V, VAL = 0.8V

|  |          |  |             | LIN  | IITS |       |
|--|----------|--|-------------|------|------|-------|
| PARAMETER  | SYMBOL   | CONDITIONS                                       | TEMPERATURE | MIN  | MAX  | UNITS |
| "Switch On" Resistance   | +RDS     | VD = 10V, IS = -10mA, S1/S2/S3/S4                | +25°C       | -    | 60   | Ω     |
|  | -RDS     | VD = -10V, IS = 10mA, S1/S2/S3/S4                | +25°C       | -    | 60   | Ω     |
| Leakage Current Into the   | +IS(OFF) | VS = +14V, VD = -14V, S1/S2/S3/S4                | +25°C       | -100 | 100  | nA    |
| Source Terminal of an "Off"<br>Switch                                      | -IS(OFF) | VS = -14V, VD = +14V, S1/S2/S3/S4                | +25°C       | -100 | 100  | nA    |
| Leakage Current into the Drain   | +ID(OFF) | VS = -14V, VD = +14V, S1/S2/S3/S4                | +25°C       | -100 | 100  | nA    |
| Terminal of an "Off" Switch  | -ID(OFF) | VS = +14V, VD = -14V, S1/S2/S3/S4                | +25°C       | -100 | 100  | nA    |
| Leakage Current from an "On"<br>Driver Into the Switch (Drain &<br>Source) | -ID(ON)  | VS = VD = +14V, S1/S2/S3/S4                      | +25°C       | -100 | 100  | nA    |
|  | -ID(ON)  | VS = VD = -14V, S1/S2/S3/S4                      | +25°C       | -100 | 100  | nA    |
| Positive Supply Current  | l(+)     | All Channels VA = 0.8V                           | +25°C       | -    | 100  | μΑ    |
|  |          | VA1 = 0V, VA2 = 4.0V and<br>VA1 = 4.0V, VA2 = 0V | +25°C       | -    | 1    | mA    |
| Negative Supply Current  | l(-)     | All Channels VA = 0.8V                           | +25°C       | -100 | -    | μΑ    |
|  |          | VA1 = 0V, VA2 = 4.0V and<br>VA1 = 4.0V, VA2 = 0V | +25°C       | -100 | -    | μA    |
| High Level Address Current   | IAH      | All Channels High                                | +25°C       | -1   | +1   | μA    |
| Low Level Address Current  | IAL      | All Channels Low                                 | +25°C       | -1   | +1   | μΑ    |
| Break-Before-Make Time<br>Delay (HS-303RH/883S and<br>HS390RH/883S Only)   | TOPEN    | RL = 300Ω, VS = +3V, (Note 1)                    | +25°C       | 2    | 300  | ns    |
| Switch Turn-On Time  | TON      | RL = 300Ω, VS = +3V, (Note 2)                    | +25°C       | -    | 500  | ns    |
| Switch Turn-Off Time   | TOFF     | RL = 300Ω, VS = +3V, (Note 2)                    | +25°C       | -    | 450  | ns    |

NOTES:

1. VAL = 0V; VAH = 5.0V

2. VAL = 0V; VAH = 4.0

|  |          |                                   |             | LIN  | IITS | UNITS |
|--|----------|-----------------------------------|-------------|------|------|-------|
| PARAMETER  | SYMBOL   | CONDITIONS                        | TEMPERATURE | MIN  | MAX  |       |
| "Switch On" Resistance   | +RDS     | VD = 10V, IS = -10mA, S1/S2/S3/S4 | +25°C       | -    | 60   | Ω     |
|  | -RDS     | VD = -10V, IS = 10mA, S1/S2/S3/S4 | +25°C       | -    | 60   | Ω     |
| Leakage Current Into the   | +IS(OFF) | VS = +14V, VD = -14V, S1/S2/S3/S4 | +25°C       | -100 | 100  | nA    |
| Source Terminal of an "Off"<br>Switch                                      | -IS(OFF) | VS = -14V, VD = +14V, S1/S2/S3/S4 | +25°C       | -100 | 100  | nA    |
| Leakage Current into the Drain Terminal of an "Off" Switch                 | +ID(OFF) | VS = -14V, VD = +14V, S1/S2/S3/S4 | +25°C       | -100 | 100  | nA    |
|  | -ID(OFF) | VS = +14V, VD = -14V, S1/S2/S3/S4 | +25°C       | -100 | 100  | nA    |
| Leakage Current from an "On"<br>Driver Into the Switch (Drain &<br>Source) | -ID(ON)  | VS = VD = +14V, S1/S2/S3/S4       | +25°C       | -100 | 100  | nA    |
|  | -ID(ON)  | VS = VD = -14V, S1/S2/S3/S4       | +25°C       | -100 | 100  | nA    |
| Positive Supply Current  | l(+)     | All Channels VA = 0V              | +25°C       | -    | 100  | μΑ    |
|  |          | All Channels VA = 15V             | +25°C       | -    | 1    | mA    |
| Negative Supply Current  | l(-)     | All Channels VA = 0V              | +25°C       | -100 | -    | μΑ    |
|  |          | All Channels VA = 15V             | +25°C       | -100 | -    | μΑ    |
| High Level Address Current   | IAH      | All Channels High                 | +25°C       | -1   | +1   | μΑ    |
| Low Level Address Current  | IAL      | All Channels Low                  | +25°C       | -1   | +1   | μA    |
| Break-Before-Make Time<br>Delay (HS-307RH/883S Only)                       | TOPEN    | RL = 300Ω, VS = +3V, (Note 1)     | +25°C       | 2    | 300  | ns    |
| Switch Turn-On Time  | TON      | RL = 300Ω, VS = +3V, (Note 1)     | +25°C       | -    | 500  | ns    |
| Switch Turn-Off Time   | TOFF     | RL = 300Ω, VS = +3V, (Note 1)     | +25°C       | -    | 450  | ns    |

TABLE 4. HS-306/307RH/883S DC POST 100K RAD (Si) ELECTRICAL CHARACTERISTICS

NOTE: 1. VAL = 0V; VAH = 15V

# TABLE 5. HS-302RH/303RH/384RH/390RH/883S DC POST BURN-IN DELTA ELECTRICAL CHARACTERISTICSGuaranteed, Per Mil-Std-883. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +4.0V, VAL = 0.8V

|  |          |                                      | GROUP A<br>SUB- |                    | LIN | IITS |       |
|--|----------|--------------------------------------|-----------------|--------------------|-----|------|-------|
| PARAMETER  | SYMBOL   | CONDITIONS                           | GROUPS          | TEMPERATURE        | MIN | МАХ  | UNITS |
| "Switch On"<br>Resistance  | +RDS     | VD = 10V, IS = -10mA,<br>S1/S2/S3/S4 | 1               | +25 <sup>0</sup> C | -5  | 5    | Ω     |
| -RD  |          | VD = -10V, IS = 10mA,<br>S1/S2/S3/S4 | 1               | +25 <sup>0</sup> C | -5  | 5    | Ω     |
| Leakage Current<br>Into the Source<br>Terminal of an "Off"<br>Switch | +IS(OFF) | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1               | +25°C              | -2  | 2    | nA    |
|  | -IS(OFF) | VS = -14V, VD = +14V,<br>S1/S2/S3/S4 | 1               | +25°C              | -2  | 2    | nA    |
| Leakage Current<br>into the Drain                                    | +ID(OFF) | VS = -14V, VD = +14V,<br>S1/S2/S3/S4 | 1               | +25 <sup>0</sup> C | -2  | 2    | nA    |
| Terminal of an "Off"<br>Switch -ID(O                                 |          | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1               | +25°C              | -2  | 2    | nA    |
| Leakage Current  | +ID(ON)  | VS = VD = +14V, S1/S2/S3/S4          | 1               | +25°C              | -2  | 2    | nA    |
| from an "On" Driver<br>Into the Switch<br>(Drain & Source)           | -ID(ON)  | VS = VD = -14V, S1/S2/S3/S4          | 1               | +25°C              | -2  | 2    | nA    |

|                                     |        |  | GROUP A        |             | LIN  | IITS |       |
|-------------------------------------|--------|--|----------------|-------------|------|------|-------|
| PARAMETER                           | SYMBOL | CONDITIONS                                       | SUB-<br>GROUPS | TEMPERATURE | MIN  | МАХ  | UNITS |
| Low Level Input<br>Address Current  | IAL    | All Channels VA = 0.8V                           | 1              | +25°C       | -100 | 100  | nA    |
| High Level Input<br>Address Current | IAH    | All Channels VA = 4.0V                           | 1              | +25°C       | -100 | 100  | nA    |
| Positive Supply                     | l(+)   | All Channels VA = 0.8V                           | 1              | +25°C       | -1   | 1    | μΑ    |
| Current                             |        | VA1 = 0V, VA2 = 4.0V and<br>VA1 = 4.0V, VA2 = 0V | 1              | +25°C       | -0.1 | 0.1  | mA    |
|                                     | l(-)   | All Channels VA = 0.8V                           | 1              | +25°C       | -1   | 1    | μΑ    |
| Current                             |        | VA1 = 0V, VA2 = 4.0V and<br>VA1 = 4.0V, VA2 = 0V | 1              | +25°C       | -1   | 1    | μA    |

### TABLE 5. HS-306RH/307RH/883S DC POST BURN-IN DELTA ELECTRICAL CHARACTERISTICS

Guaranteed, Per Mil-Std-883. Unless Otherwise Specified: V- = -15V, V+ = +15V, VAH = +11.0V, VAL = 3.5V

|   |          |                                      | GROUP A   |                    | LIN  | IITS |       |
|---|----------|--------------------------------------|-----------|--------------------|------|------|-------|
| PARAMETER   | SYMBOL   | CONDITIONS                           | SUBGROUPS | TEMPERATURE        | MIN  | MAX  | UNITS |
| "Switch On" Resistance  | +RDS     | VD = 10V, IS = -10mA,<br>S1/S2/S3/S4 | 1         | +25 <sup>0</sup> C | -5   | 5    | Ω     |
|   | -RDS     | VD = -10V, IS = 10mA,<br>S1/S2/S3/S4 | 1         | +25 <sup>0</sup> C | -5   | 5    | Ω     |
| Leakage Current Into the<br>Source Terminal of an<br>"Off" Switch | +IS(OFF) | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1         | +25°C              | -2   | 2    | nA    |
|   | -IS(OFF) | VS = -14V, VD = +14V,<br>S1/S2/S3/S4 | 1         | +25°C              | -2   | 2    | nA    |
| Leakage Current into the<br>Drain Terminal of an "Off"<br>Switch  | +ID(OFF) | VS = -14V, VD = +14V,<br>S1/S2/S3/S4 | 1         | +25 <sup>0</sup> C | -2   | 2    | nA    |
| Switch  | -ID(OFF) | VS = +14V, VD = -14V,<br>S1/S2/S3/S4 | 1         | +25°C              | -2   | 2    | nA    |
| Leakage Current from an   | +ID(ON)  | VS = VD = +14V, S1/S2/S3/S4          | 1         | +25°C              | -2   | 2    | nA    |
| "On" Driver Into the Switch<br>(Drain & Source)                   | -ID(ON)  | VS = VD = -14V, S1/S2/S3/S4          | 1         | +25°C              | -2   | 2    | nA    |
| Low Level Input Address<br>Current                                | IAL      | All Channels VA = 3.5V               | 1         | +25°C              | -100 | 100  | nA    |
| High Level Input Address<br>Current                               | IAH      | All Channels VA = 11V                | 1         | +25 <sup>0</sup> C | -100 | 100  | nA    |
| Positive Supply Current   | l(+)     | All Channels VA = 0V                 | 1         | +25°C              | -1   | 1    | μA    |
|   |          | All Channels VA = 15V                | 1         | +25°C              | -1   | 1    | μA    |
| Negative Supply Current   | l(-)     | All Channels VA = 0V                 | 1         | +25°C              | -1   | 1    | μΑ    |
|   |          | All Channels VA = 15V                | 1         | +25°C              | -1   | 1    | μΑ    |

# Specifications HS-3XXRH/883S

### TABLE 6. APPLICABLE SUBGROUPS

|                     |              |             | GROUP A SUB                           | GROUPS                    |
|---------------------|--------------|-------------|---------------------------------------|---------------------------|
| CONFORMA            | NCE GROUPS   | METHOD      | TESTED                                | RECORDED                  |
| Initial Test        |              | 100%/5004   | 1, 7, 9                               | 1, (Note 2)               |
| Interim Test        |              | 100%/5004   | 1, 7, 9, Deltas                       | 1, Deltas, (Note 2)       |
| PDA                 |              | 100%/5004   | 1, 7, Deltas                          |                           |
| Final Test          |              | 100%/5004   | 2, 3, 8A, 8B, 10, 11                  |                           |
| Group A (Note 1)    |              | Sample/5005 | 1, 2, 3, 7, 8A, 8B, 9, 10, 11         |                           |
| Group B             | Subgroup B-5 | Sample/5005 | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas | 1, 2, 3, Deltas, (Note 2) |
|                     | Subgroup B-6 | Sample/5005 | 1, 7, 9                               |                           |
| Group D             | •            | Sample/5005 | 1, 7, 9                               |                           |
| Group E, Subgroup 2 |              | Sample/5005 | 1, 7                                  |                           |

NOTES:

1. Alternate Group A testing in accordance with Method 5005 of MIL-STD-883 may be exercised.

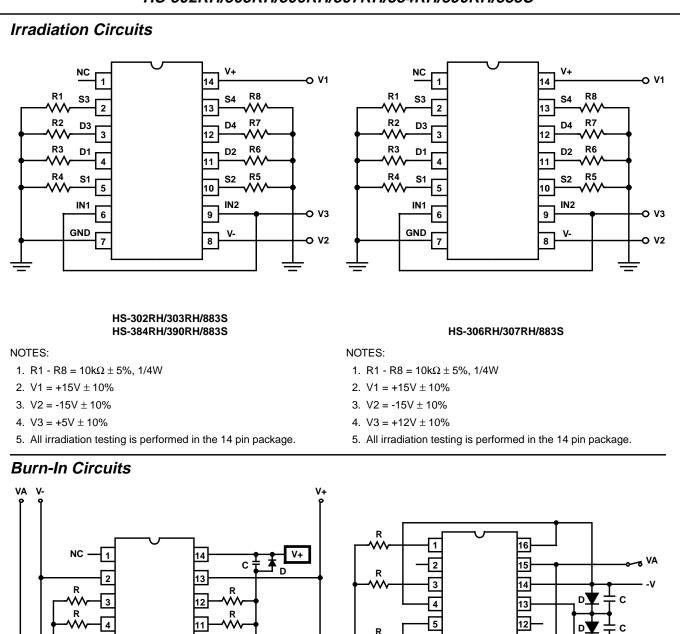
2. Table 5 parameters on.y.

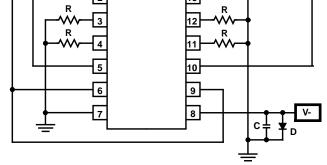
### Intersil Space Level Product Flow

NOTES:

- 1. Failures from subgroup 1, 7 and deltas are used for calculating PDA. The maximum allowable PDA = 5% with no more than 3% of the failures from subgroup 7.
- 2. Radiographic (X-Ray) inspection may be performed at any point after serialization as allowed by Method 5004.
- 3. Alternate Group A testing may be performed as allowed by MIL-STD-883, Method 5005.
- 4. Data Package Contents:
  - Cover Sheet (Intersil Name and/or Logo, P.O. Number, Customer Part Number, Lot Date Code, Intersil Part Number, Lot Number, Quantity).
  - Wafer Lot Acceptance Report (Method 5007). Includes reproductions of SEM photos with percent of step coverage.
  - GAMMA Radiation Report. Contains Cover page, disposition, Rad Dose, Lot Number, Test Package used, Specification Numbers, Test equipment, etc. Radiation Read and Record data on file at Intersil.
  - X-Ray report and film. Includes penetrometer measurements.
  - Screening, Electrical, and Group A attributes (Screening attributes begin after package seal).
  - Lot Serial Number Sheet (Good units serial number and lot number).
  - Variables Data (All Delta operations). Data is identified by serial number. Data header includes lot number and date of test. (See Table 6)
  - Group B and D attributes and/or Generic data.
  - The Certificate of Conformance is a part of the shipping invoice and is not part of the Data Book. The Certificate of Conformance is signed by an authorized Quality Representative.

## HS-302RH/303RH/306RH/307RH/384RH/390RH/883S





#### STATIC CONFIGURATION HS-302RH/303RH/306RH/307RH/883S

#### NOTES:

- 1. R = 10K $\Omega \pm$  5%, 1/4W (4 per position)
- 2. C =  $0.01\mu$ F minimum (per position) or  $0.1\mu$ F minimum per row
- 3. D = IN4002 (or equivalent)
- 4. +V = +15.5V  $\pm$  0.5V, -V = -15.5V  $\pm$  0.5V
- 5. VA = +15.5V  $\pm$  0.5V for 306RH/307RH
- 6. VA = +5.5V  $\pm$  0.5V for 302RH/303RH

### STATIC CONFIGURATION HS-384RH/390RH/883S

11

10

9

### NOTES:

R

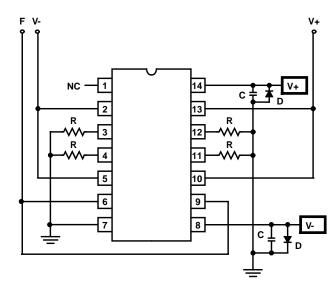
1. R = 10K $\Omega \pm$  5%, 1/4W (4 per position)

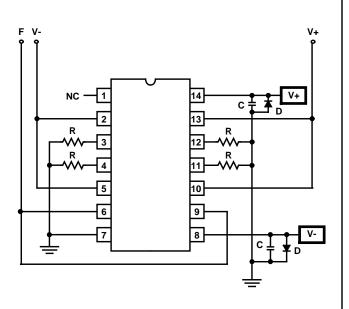
8

- 2. C = 0.01 $\mu$ F minimum (per position) or 0.1 $\mu$ F minimum per row
- 3. D = IN4002 (or equivalent)
- 4.  $+V = +15.5V \pm 0.5V$ ,  $-V = -15.5V \pm 0.5V$
- 5. VA = +5.5V  $\pm$  0.5V

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## Burn-In Circuits (Continued)





### DYNAMIC CONFIGURATION HS-302RH/303RH/883S

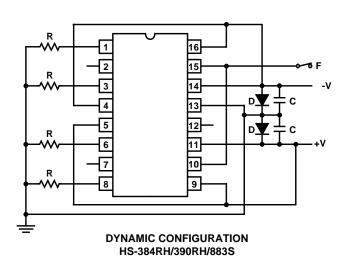
#### NOTES:

- 1. R = 10K $\Omega \pm$  5%, 1/4W (4 per position)
- 2. C = 0.01  $\mu F$  minimum (per position) or 0.1  $\mu F$  minimum per row
- 3. D = IN4002 (or equivalent)
- 4. F = 100kHz square wave, 50% duty cycle, VL = 0.8V max., VH = 5.5V  $\pm$  0.5V
- 5. +V = +15.5V  $\pm$  0.5V, -V = -15.5V  $\pm$  0.5V

### DYNAMIC CONFIGURATION HS-306RH/307RH/883S

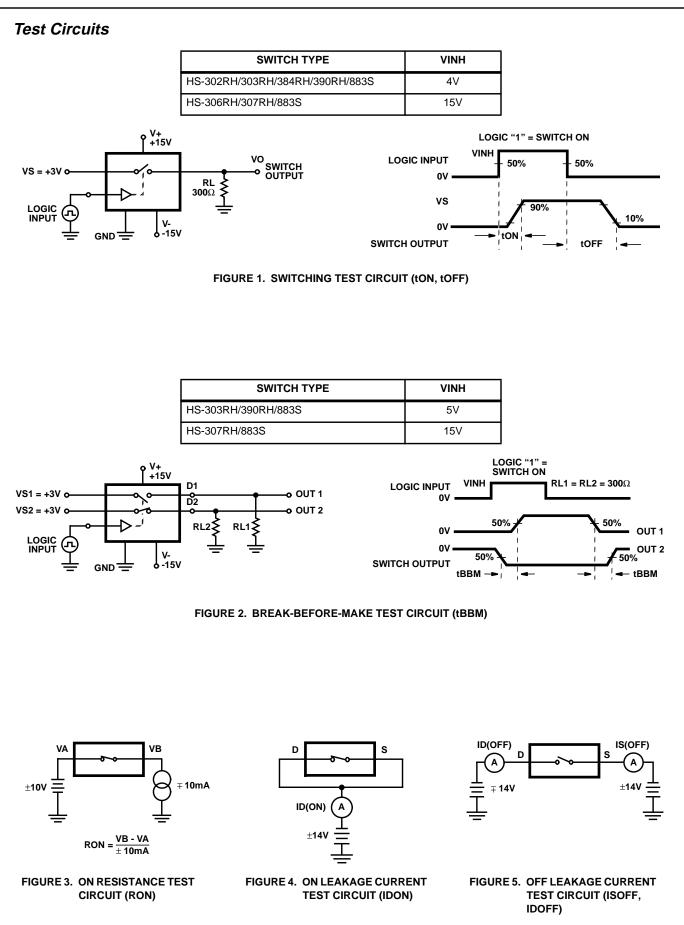
### NOTES:

- 1. R = 10K $\Omega \pm$  5%, 1/4W (4 per position)
- 2. C =  $0.01\mu$ F minimum (per position) or  $0.1\mu$ F minimum per row
- 3. D = IN4002 (or equivalent)
- 4. F = 100kHz square wave, 50% duty cycle, VL = 0.8V max., VH = 14V  $\pm$  1V
- 5. +V = +15.5V  $\pm$  0.5V, -V = -15.5V  $\pm$  0.5V



### NOTES:

- 1. R = 10K $\Omega\pm$  5%, 1/4W (4 per position)
- 2. C = 0.01 $\mu$ F minimum (per position) or 0.1 $\mu$ F minimum per row
- 3. D = IN4002 (or equivalent)
- 4. F = 100kHz square wave, 50% duty cycle, VL = 0.8V max., VH = +5.5V  $\pm 0.5V$
- 5. +V = +15.5V  $\pm$  0.5V, -V = -15.5V  $\pm$  0.5V



## Metallization Topology

### DIE DIMENSIONS:

Die Size: 2130 x 1930 $\mu m$  Die Thickness: 11  $\pm 1$  mils

WORST CASE CURRENT DENSITY: 1.732e05 A/cm<sup>2</sup> SUBSTRATE POTENTIAL: Unbiased PROCESS: DI Linear Metal Gate CMOS

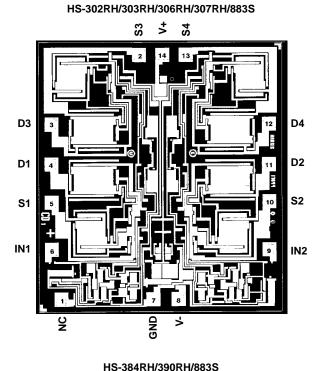
# METALLIZATION:

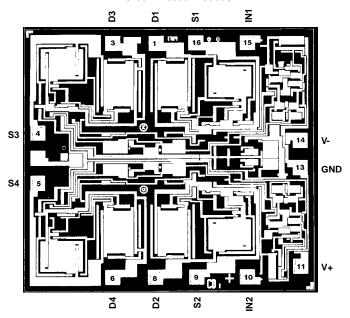
Type: AI, 12.5kÅ  $\pm$  2kÅ Back: Gold

### **GLASSIVATION:**

Type: SiO<sub>2</sub> Thickness: 8kÅ  $\pm$  1kÅ

### Metallization Mask Layout





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